

OTHER CIRCUITS

Some circuits work for both transmitting and receiving and are described as follows:

PLL CIRCUIT: VFO unit PB-1465
 FIX unit PB-1453
 LOCAL unit PB-1454
 PLL unit PB-1455

The FT-221R utilizes a phase lock loop system for the heterodyne oscillator providing a stable signal varying from 133.3 through 137.3 MHz to cover the entire 2 meter band.

VFO UNIT (PB-1465)

The VFO module board is installed in the VFO chassis. The VFO (variable frequency oscillator) Q₁₃₀₁, 2SC372Y, generates an 8,000 to 8,500 kHz signal and produces a 500 kHz main tuning dial range. Frequency drift is minimized through the use of a temperature compensation circuit utilizing a differential trimmer capacitor. The signal is fed through the amplifier buffer stage Q₁₃₀₂, 2SK19GR, and Q₁₃₀₃, 2SC372Y, to pin 11 of the FIX oscillator board. The buffer amplifier provides isolation and amplification of the VFO signal.

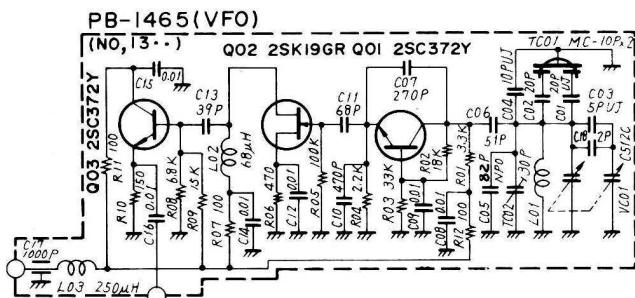


Figure 18

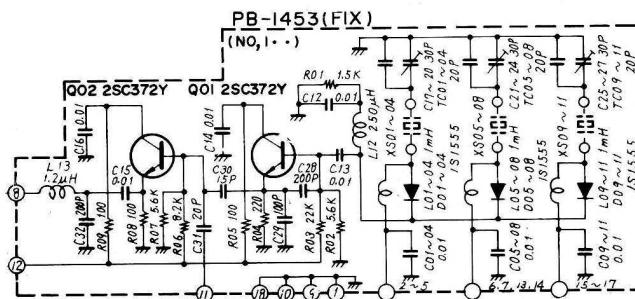


Figure 19

FIX UNIT (PB-1453)

In addition to normal VFO operation, 11 crystals may be selected for crystal controlled operation with the selector switch located on the front panel of the transceiver.

The FIX channel crystal oscillator Q₁₀₁, 2SC372Y, oscillates at the frequency of the crystal selected by the diode switch D₁₀₁ through D₁₁₁, 1S1555. The output is fed from pin 8 through the buffer amplifier Q₁₀₂, 2SC372Y, to the PLL unit.

The signal from the VFO also passes through this buffer stage to the PLL unit.

The crystal frequency falls between 8,000 and 8,500 kHz and is determined as follows.

$$f_x = f_0 - f_1$$

where f₁ is given in Table 1 on page 12 and f₀ is the operating frequency.

LOCAL UNIT (PB-1454)

This oscillator generates a heterodyne signal which is used to convert the VCO (voltage controlled oscillator) signal to an 8,000 to 8,500 kHz signal, which is used for the comparison of the phase with that of the reference (VFO) signal.

The crystal controlled oscillator Q₂₀₁, 2SC372Y, oscillates at the fundamental frequency of the crystal. A varactor diode D₂₂₆, 1SV50, connected to the base of Q₂₀₁, is used as a clarifier to shift the oscillator frequency for receiver off-set tuning.

The output from the oscillator is fed to the frequency multiplier stage, Q₂₀₂ and Q₂₀₃, 2SC784R, producing the ninth harmonic at its output. The crystal is selected by the diode switch connected to the band switch. The relation between the frequency and band is shown on Table 2. The multiplied signal is then fed from pin 3 to the PLL unit.

For repeater operation, a fundamental crystal at 14.1333 MHz, X210, is used to generate a heterodyne signal of 127.2 MHz which is 600 kHz higher than the normal heterodyne signal when the band switch is set to the 146.5 MHz segment and X211 (fundamental frequency 14.3222 MHz) is used to generate 128.3 MHz signal which is 600

kHz higher than the normal heterodyne signal when the band switch is set to the 147.0 segment.

A relay, RL₁₀₀₁ in the tone burst unit is used to select the above crystals with the Repeater switch, S₈, in the ON position. When the Normal-Reverse switch, S₉, is set to the NOR position, the relay selects the repeater crystal on transmit that shifts the transmitting frequency down 600 kHz in the 146.5 MHz segment and shifts up 600 kHz in the 147.0 MHz band. The main VFO tuning dial indicates the received frequency.

With S₉ in the REV position, the relay selects the repeater crystal on receive that shifts the receiver frequency down 600 kHz in the 146.5 MHz segment and shifts up 600 kHz in the 147.0 MHz segment. The main tuning dial now indicates the transmitted frequency.

BAND	Crystal No.	Crystal Frequency	Local Frequency
		MHz	MHz
144.0	X ₂₀₁	13.9222	125.3
144.5	X ₂₀₂	13.9777	125.8
145.0	X ₂₀₃	14.0333	126.3
145.5	X ₂₀₄	14.0888	126.8
146.0	X ₂₀₅	14.1444	127.3
146.5	X ₂₀₆	14.2000	127.8
	X ₂₁₀	*14.1333	127.2
147.0	X ₂₀₇	14.2555	128.3
	X ₂₁₁	*14.3222	128.9
147.5	X ₂₀₈	14.3111	128.8

*Repeater for US Model.

Table 2

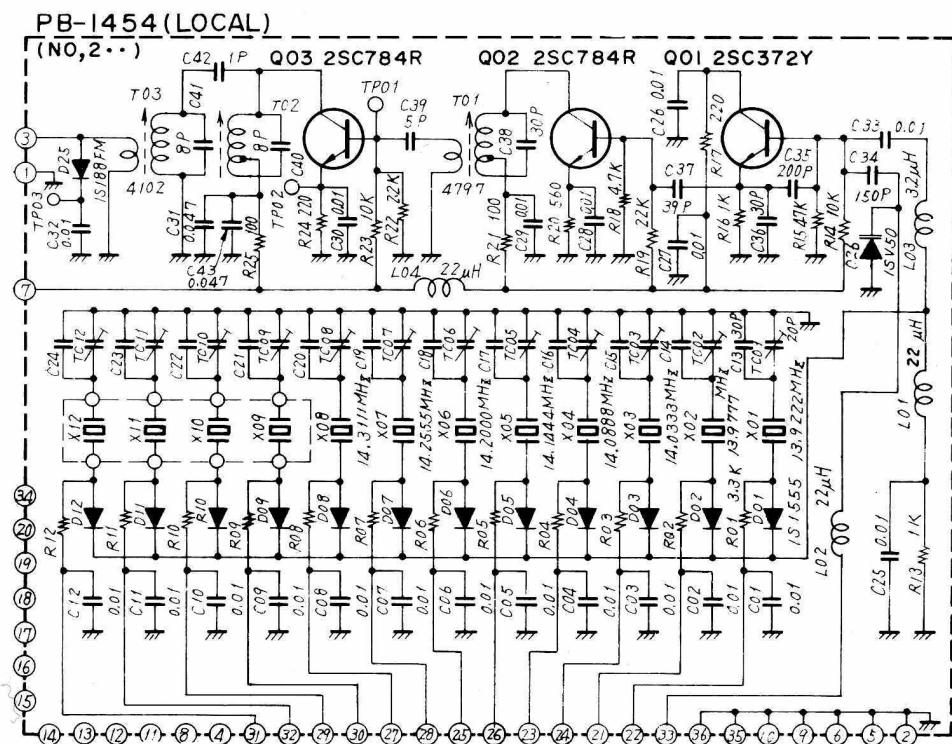


Figure 20

PLL UNIT (PB-1455)

This unit generates a heterodyne signal for the transmitter and receiver mixer in conjunction with the Phase Lock oscillator.

A voltage controlled oscillator Q₃₀₅, 2SK19GR, generates a signal between 133.3 MHz and 137.3 MHz which is determined by L₃₀₁, TC₃₀₁, C₃₂₄, D₃₀₅ and D₃₀₆. The varactor diode, D₃₀₅, changes the frequency by the DC voltage which is delivered from the phase detector amplifier Q₃₀₁, 2SK19GR. The varactor diode, D₃₀₆, is used to shift the oscillating frequency in accordance with the band switch setting for a stable lock of the VCO. The output from the VCO, Q₃₀₅, is fed through a two stage buffer amplifier Q₃₀₆, 2SK19GR, Q₃₀₇, 2SC784R, to the mixers, Q₄₀₅ in receive, Q₅₀₁ and Q₅₀₂ in transmit.

A portion of the output from Q₃₀₆ is amplified through the buffer amplifier Q₃₀₄, 2SC372Y, and is fed to the mixer Q₃₀₃, 2SC372Y, where the signal from local oscillator unit is converted into a 8,000 to 8,500 kHz comparison signal.

This comparison signal is amplified by the amplifier Q₃₀₂, μ A703HC and fed to the phase detector circuit consisting of diodes, D₃₀₃ and D₃₀₄, 1S-1007.

The phase detector compares the phase of the comparison signal with that of the reference signal which is fed through pin 17 from the FIX unit (VFO or FIX crystal signal), and any phase difference is converted into an error correcting voltage. This error voltage is amplified by Q₃₀₁, 2SK19GR, and fed to the varactor diode D₃₀₅, 1SV50, which changes the output signal phase to track the input.

The programmable unijunction transistor D₃₀₁, N13T1, generates a sawtooth wave when the VCO is unlocked. The sawtooth wave is used to lock the VCO. A portion of it is fed to the inverter Q₃₀₈, and rectified by Q₃₁₀ 1S1555.

The rectified voltage causes Q₃₀₉, 2SC372Y, to conduct and its emitter voltage is used to conduct Q₆₀₇ in the AF unit thus shorting the audio input to quiet the receiver when the PLL is unlocked.

In transmit, this voltage controls Q₅₀₇ in the EXCITER unit causing Q₅₀₆ cut off to disable the exciter stages. Thus, the transmitter and receiver stop functioning when the VCO is unlocked. With this voltage, a multivibrator Q₃₀₈, TP4011AN, produces a blanking pulse which controls the pilot lamp driver Q₃₁₀, MPSA13, causing the pilot lamp to flicker indicating VCO unlock.

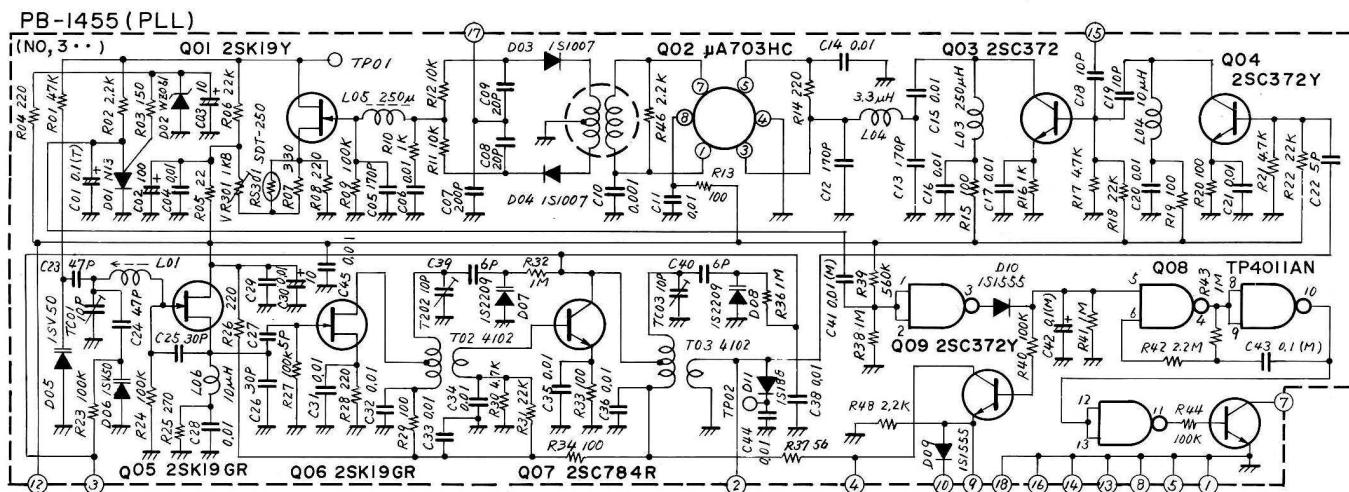


Figure 21

MARKER UNIT (PB-1459)

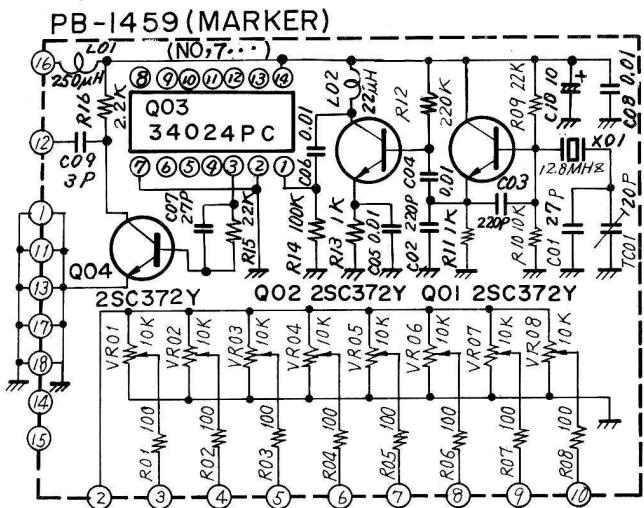


Figure 22

The crystal marker generator Q_{701} , 2SC372Y, generates a 12.8 MHz signal, and its output is fed through the buffer amplifier Q_{702} , 2SC372Y, to the frequency divider Q_{703} , 34024PC, where the 12.8 MHz signal generates a 100 kHz marker signal. The marker signal is fed through a buffer amplifier Q_{704} , 2SC372Y to the RX RF unit. When the marker switch is ON, the antenna relay is activated to disconnect the antenna.

Potentiometers VR_1 through VR_8 are installed in this board. These potentiometers are set to change the tuning frequency of the VCO and the exciter tuning circuits.

TONE BURST UNIT (PB-1461)

The tone burst signal is automatically transmitted in the following manner. When the PTT switch of the microphone is pressed momentarily before a normal transmission, the rapid voltage change in the PTT circuit causes a pulse to be fed to the tone burst control circuit consisting of Q_{1001} , Q_{1002} , Q_{1003} , TP4011AN, and Q_{1004} , TP4049AN, thus activating the tone burst oscillator Q_{1003} , TP4011AN.

Normal push-to-talk operation does not produce a pulse to activate the tone burst oscillator.

The tone frequency may be adjusted to any frequency between 1000 to 2000 Hz with VR_{1002} and the tone burst duration may be adjusted with VR_{1001} . The tone signal output level may be adjusted with VR_{1003} . The output from the tone burst oscillator is fed through the buffer Q_{1006} , 2SK19GR, to pin 29 in the MIC AMP unit.

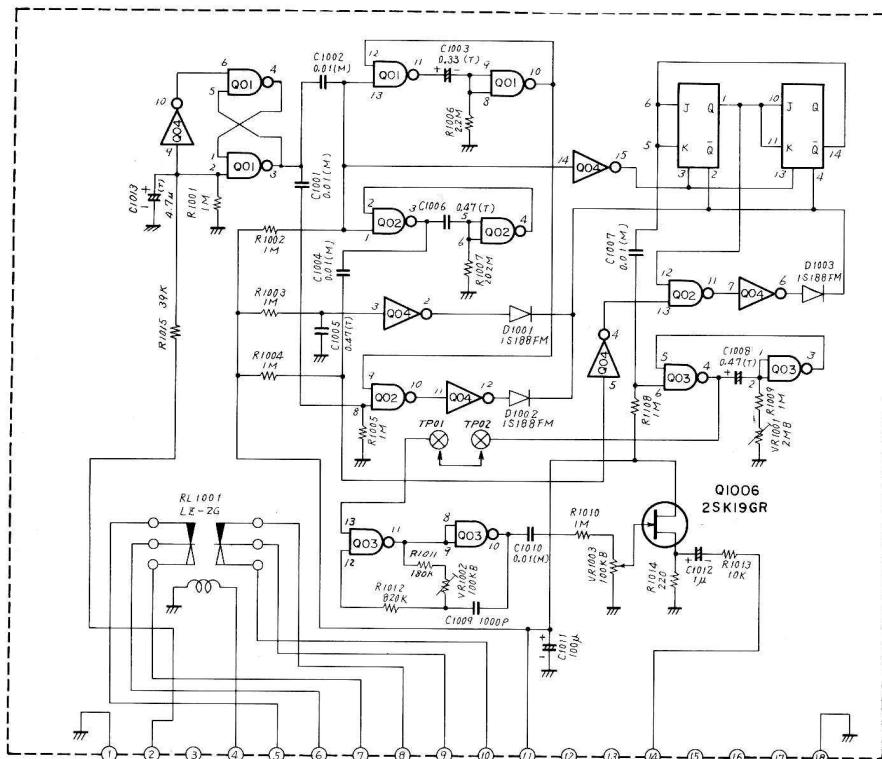


Figure 23 TONE BURST UNIT PB-1461

POWER SUPPLY & REGULATOR UNIT (PB-1469)

The power supply has been designed to operate from 100/110/117/200/220 or 234 volts AC 50/60 Hz, or 12 volts DC, negative ground. Inserting the appropriate power plug into the rear panel receptacle makes the necessary connections to operate the supply in either mode, AC or DC.

For AC operation, the DC voltage is supplied from the bridge connected rectifier unit D₁₅₀, M4B-5, which is connected to a 20 volt, 3.5 amps secondary winding of the power transformer. The DC voltage is regulated at 13.5 volts by the voltage regulator circuit consisting of Q₁₅₀₁, 2SD313D, and Q₁, 2SD114.

Since such circuits as the VFO, local oscillator PLL circuit, require an extremely stabilized voltage, the 13.5 volts DC voltage is further stabilized at 8 volts by the voltage regulator Q₁₅₀₃, 2SC735Y, Q₁₅₀₄, 2SD313D, and Q₁₅₀₅, 2SC372Y.

For DC operation, the positive voltage is connected to pin 3 and the negative voltage to pin 4, of the power receptacle, J₁. To protect the circuits from any reverse connection of the DC voltage, D₁, DS130YD, conducts heavily in the reverse polarity connection to blow the line fuse in the DC cord. It is placed between pin 3 and ground on J₁.

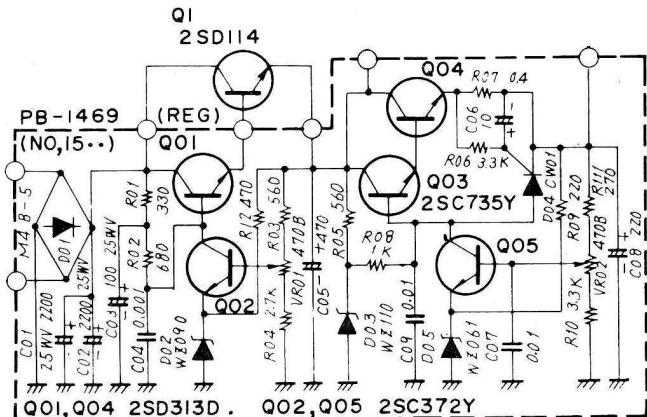
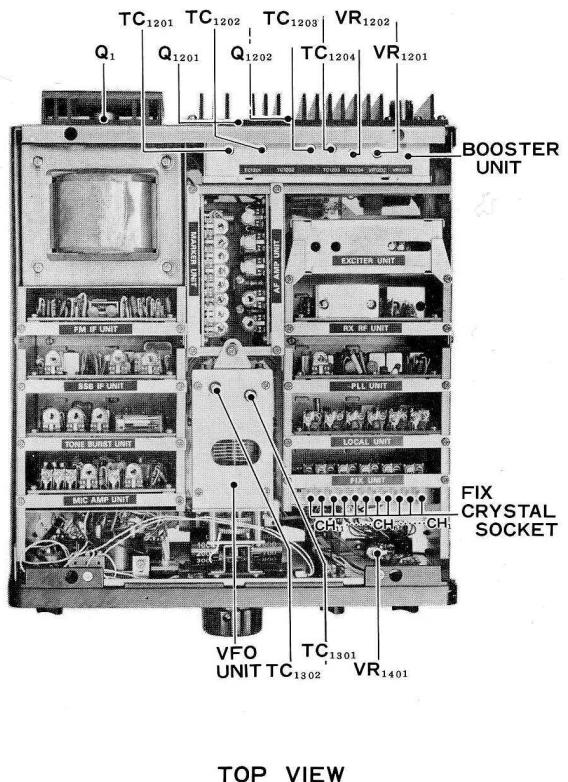
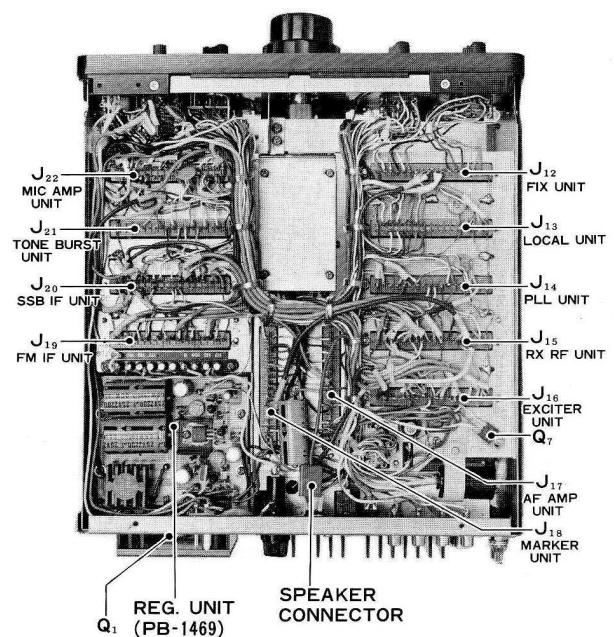


Figure 24



TOP VIEW



BOTTOM VIEW

Figure 26

MAINTENANCE & ALIGNMENT

GENERAL

Your model FT-221R transceiver has been carefully aligned and tested at factory prior to shipment. The reliability of the solid-state devices used in the FT-221R should provide years of trouble free service if the transceiver is not abused and normal, routine maintenance is carried out.

The following precautions should be observed to prevent damage to the transceiver:

- (1) Do not interchange the AC and DC power cords.
- (2) Do not apply any AC voltage other than the voltage determined by the transformer wiring.
- (3) Do not exceed 14 volts DC, at the POWER receptacle, on DC operation. When operating mobile, check the battery voltage under the load (transmitter "keyed" in FM mode) with the engine running fast enough so the ammeter shows a "charge". In addition, do not operate the FT-221R if the supply voltage is below 12 volts DC.
- (4) Avoid direct exposure to sunshine or water.

ROUTINE MAINTENANCE

Routine maintenance should be limited to keeping the transceiver clean, and periodic performance checks of the transmitter RF power output and receiver sensitivity.

Cleaning:

When the transceiver has been used in dusty or sandy areas, the interior should be periodically cleaned. A vacuum-cleaner, or low pressure air source should be used, while any accumulated dirt may be removed with a soft brush. Check that the interior is thoroughly dry before replacing the case and/or operating the equipment. Wipe the exterior with a damp cloth whenever required.

PERFORMANCE CHECKS

Make all performance checks at 13.5 volts DC (under load) or AC with the appropriate voltage as determined by the transformer wiring.

Check the transmitter output as follows:

- (a) Connect a suitable 50 ohm dummy load/RF wattmeter to the ANT receptacle.
- (b) Set the MODE switch to FM and key the transmitter while observing the power output. The power should be approximately 10 watts, and the S-meter should read between 6 and 8.
- (c) Set the MODE switch to SSB and key the transmitter. Speak normally into the microphone. The output meter should show 3 to 5 watts mean value.

Check the receiver sensitivity as follows:

- (a) Connect an AC VTVM to the SP receptacle, set the MODE switch to FM and set the SQUELCH control fully counter-clockwise.
- (b) Connect the RF output of a precision, VHF signal generator to the ANT receptacle and with no signal input note the VTVM reading. Adjust the VOLUME control and VTVM range, as required, to obtain an approximate full scale reading. (DO NOT change the VOLUME control setting after this adjustment is made.)
- (c) Set the signal generator to the receiving frequency of the transceiver and adjust the output amplitude of the signal generator until the VTVM reads 1/10th (20 dB decrease) of the reading in step (b). The signal generator output voltage at this point is the 20 dB quieting sensitivity, and should be approximately $0.3\mu\text{V}$.
- (d) Set the MODE switch to SSB position and connect the AC VTVM to the speaker output. Apply an unmodulated, $0.5\mu\text{V}$ signal, from the standard signal generator and tune the transceiver for a maximum VTVM reading.
- (e) Set the RF GAIN control to the fully clockwise position and adjust the AF GAIN control for a 450 mV VTVM reading.
- (f) Reduce the signal generator output and read the VTVM reading. The VTVM reading should be less than 45 mV for a 10 dB S/N ratio.

If the above performance checks indicate a need for realignment it is recommended that the transceiver be returned to the dealer for alignment. The alignment procedures require special test equipment and techniques not normally available to the average owner. Attempts to realign the tuned

circuits without proper test equipment will result in degraded performance of the transceiver.

ALIGNMENT

SOME OF THE FOLLOWING ALIGNMENT PROCEDURES REQUIRE SPECIAL TEST EQUIPMENT AND TECHNIQUES AND SHOULD ONLY BE DONE BY AN EXPERT TECHNICIAN.

AF AMP UNIT

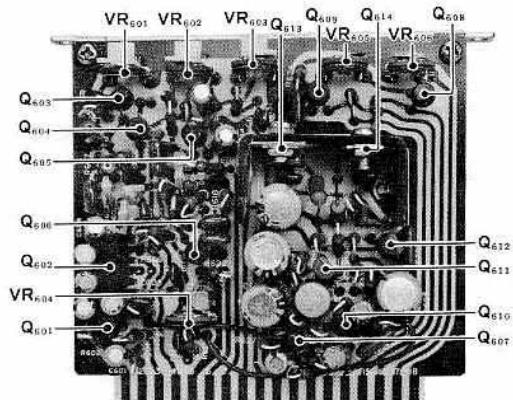


Figure 27

(1) CW Break-In

Adjust VR₆₀₁, DELAY control, for a suitable release time.

(2) CW Sidetone Level

Adjust VR₆₀₄ for a suitable side tone level.

(3) Relay Sensitivity & Antitrip

Set the controls as follows:

VR₆₀₂ RELAY Fully CCW
MIC GAIN Fully CCW
VOX GAIN PTT
MODE LSB or USB

Slowly rotate the RELAY control, VR₆₀₂, until the relay activates, then return the control carefully counter clockwise until the relay releases. This release point is the proper setting for the RELAY sensitivity control. Set the MIC GAIN control to the 2 o'clock position and the VOX control on the front panel to the 12 o'clock position. Speaking normally into the microphone, make sure that your voice activates the relay. Tune in a signal and adjust the AF GAIN on the front panel to a comfortable listening level. Set the ANTITRIP

control, VR₆₀₃, to the minimum point that will prevent the speaker output from tripping the VOX. Adjust the DELAY control, VR₆₀₁, for a suitable relay release time.

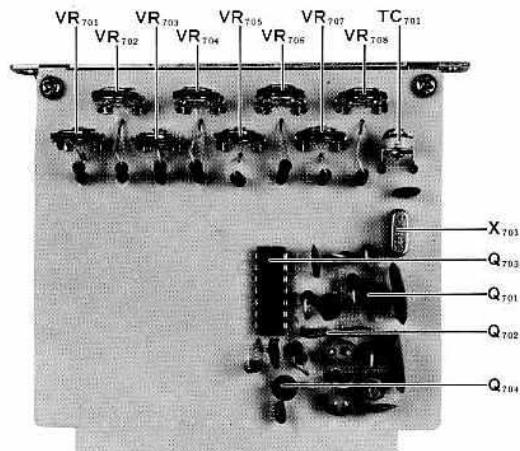
(4) Discriminator Meter Center

Set the controls as follows:

CHANNEL VFO
MODE FM
DISC OFF (down position)
RF GAIN Fully CW
MARKER ON (up position)

Tune the transceiver for maximum S-meter reading at a marker signal. This maximum reading has a 3 kHz width and the VFO should be set to the center of the signal. Turn the DISC switch on and adjust the center potentiometer, VR₆₀₅, until the meter indicates mid point on the scale. Check that the meter moves equally toward both ends when the VFO frequency is shifted equally up or down. Shift the VFO frequency 10 kHz lower than the zero center meter indication, and adjust the DISC potentiometer, VR₆₀₆, until the meter indicates 2.

MARKER UNIT



MARKER UNIT (PB-1459)

Figure 28

(1) Frequency Adjustment

Connect a frequency counter, through a 100 PF capacitor, to the collector of Q₇₀₂, 2SC372Y. Adjust TC₇₀₁ to set the crystal frequency to 12.8MHz.

When the counter is not available, use another H.F. receiver and calibrate the 100kHz signal against WWV or JJJ.

(2) Voltage Adjustment for the Varicap Tuning Circuit

Measure the voltage at pins 3, 4, 5, 6, 7, 8, 9 and 10 with a VTVM connected between the pins and ground.

Adjust the appropriate potentiometer, VR₇₀₁ to VR₇₀₈, for following pin voltages:

Pin No.	3	4	5	6	7	8	9	10
Adjust. VR No.	701	702	703	704	705	706	707	708
Volt. DC. V.	2.0	2.5	3.0	3.5	4.0	4.5	5.0	5.5

Table 3

SSB IF UNIT

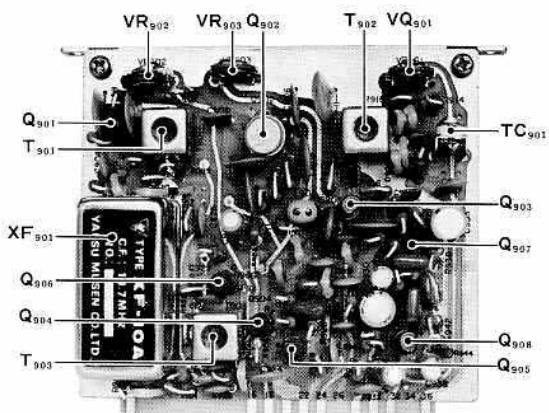


Figure 29

(1) S Meter Setting

Disconnect the antenna from the coax receptacle. Set the MODE switch to the AM mode. Set the RF GAIN control on the front panel to the fully clockwise position. Adjust VR₉₁₃ (ZERO) until the meter indicates zero. Then set the RF GAIN control to the fully counter clockwise position. Adjust VR₉₀₂ (FULL SCALE) until the meter indicates full scale. Repeat above procedures until the meter indicates zero and full scale with above mentioned RF GAIN settings.

(2) Carrier Balance (SSB Receive)

Disconnect the antenna.

Set the MODE switch to either the LSB or USB modes, and the RF GAIN control fully counter clockwise. Adjust VR₉₀₁ and TC₉₀₁ (CARRIER BALANCE) alternately until the S-meter indicates full scale. Change the MODE switch to CW position and check if the S-meter indicates exactly full scale.

MIC AMP UNIT

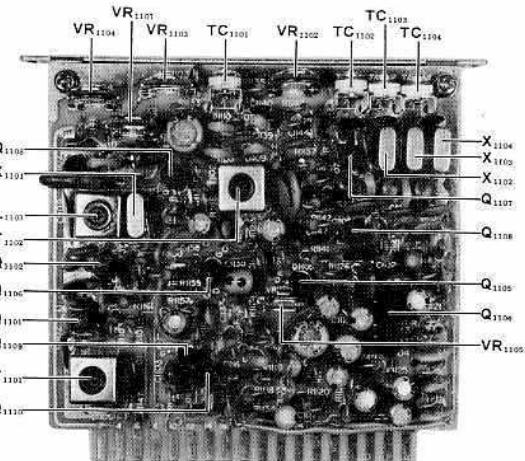


Figure 30

(1) SSB Carrier Frequency

Connect a dummy load, such as the YAESU YP-150, to the antenna receptacle and the output of an audio oscillator to the microphone input. Set the MODE switch to an SSB mode. Apply 1 kHz audio signal to the microphone input and adjust the MIC GAIN control or the output level from the audio oscillator for 10 watts RF output on the dummy load. Change the audio frequency to 350 Hz, and adjust TC₁₁₀₂ for LSB and TC₁₁₀₃ for USB to obtain 2.5 watts output. Check if the power output decreases to 2.5 watts when the audio frequency is moved to approximately 2600 Hz.

(2) AM and CW Carrier Frequency

Tune the transceiver in the USB mode and monitor the transmitted USB signal for the most natural voice quality while using another receiver. Change the mode of the transceiver to AM (with the monitor receiver in the USB mode), and adjust TC₁₁₀₄ for a zero beat against a carrier signal.

(3) Carrier Balance (SSB Transmit)

Connect a dummy load to the antenna receptacle and the RF probe of a VTVM to the inner conductor of coax cable at the antenna receptacle. Set the MODE switch to the LSB mode. Set the MIC GAIN control to the fully CCW position. Set the VOX switch to MOX position. Adjust VR₁₁₀₂ and TC₁₁₀₁ (CARRIER BALANCE) alternately to minimize the VTVM reading.

Repeat this procedure until a minimum reading is obtained equally for both side bands.

(4) CW Carrier Level

Set the CW level control, VR₁₁₀₅, to the point where the output power starts to saturate.

FIX UNIT

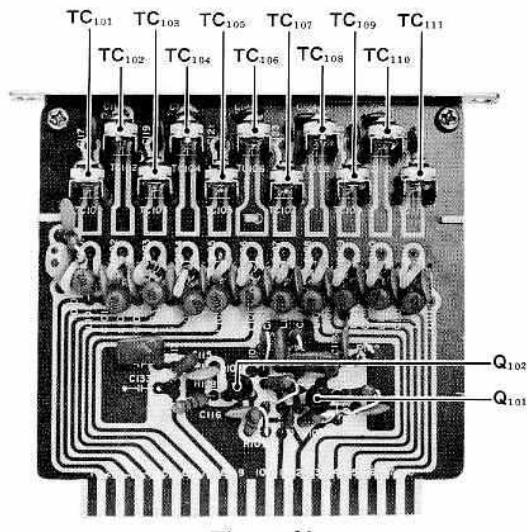


Figure 31

The crystal frequency may be precisely adjusted with TC₁₀₁ to TC₁₁₁ for on-frequency crystal controlled operation.

LOCAL UNIT

Set the MODE switch to USB, the BAND switch to 144.0, the CHANNEL switch to VFO, the MARK switch to OFF and the RPT switch to the OFF position. Connect a frequency counter to TP₂₀₁ and adjust the oscillator frequency to 41.7666 MHz with TC₂₀₁. Set the MARK switch to the ON position and zero beat against the marker signal at 144.0 MHz on the VFO tuning

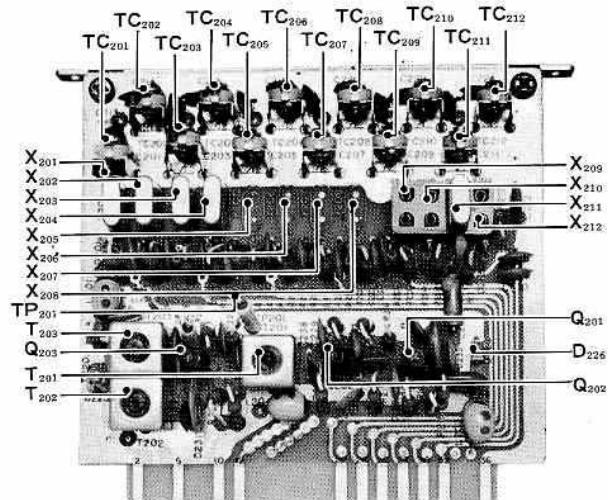
dial. Set the BAND switch to 144.5 MHz and adjust TC₂₀₂ to zero beat, then adjust TC₂₀₃ for 145.0 MHz, TC₂₀₄ for 145.5 MHz, TC₂₀₅ for 146.0 MHz, TC₂₀₆ for 146.5 MHz, TC₂₀₇ for 147.0 MHz and TC₂₀₈ for 147.5 MHz for a zero beat against the marker signal.

For the U.S. model, set the RPT switch to REV, the AUX/600 kHz switch to 600 kHz and the BAND switch to 146.5. Adjust TC₂₁₀ for zero beat. Change the BAND switch to 147.0 and adjust TC₂₁₁ for zero beat. For the European model, set the BAND switch to 145.0 and adjust TC₂₁₀ for zero beat. During the above repeater frequency adjustment, the VFO dial is set to the zero beat obtained in the preceding adjustment.

For the frequency split other than 600 kHz, the crystal calculated by the formular in page 12 is installed in X₂₀₉ socket for 146.5 MHz band and in X₂₁₂ socket for 147.0 MHz band. Set the AUX/600 kHz switch to AUX position.

For the split frequency in 100 kHz order, such as 800, 900 or 1000 kHz, use the internal marker signal to calibrate as described in 600 kHz procedures. Adjust TC₂₀₉ for zero beat on 146.5 MHz band and TC₂₁₂ on 147.0 MHz band.

When the split frequency is not in 100 kHz order, such as 850 kHz or 940 kHz, the internal marker signal can not be used. In such a case, connect a precise frequency counter between TP₂₀₁ and ground and adjust TC₂₀₉ or TC₂₁₂ for exact frequency which is 3rd harmonics of the crystal frequency given from the formular. For example, the counter frequency should be 42.31666 MHz for 850 kHz split on 146.5 MHz band, as the crystal frequency is $(127.8 - 0.85) \div 9 = 14.1055$ MHz.



PLL UNIT

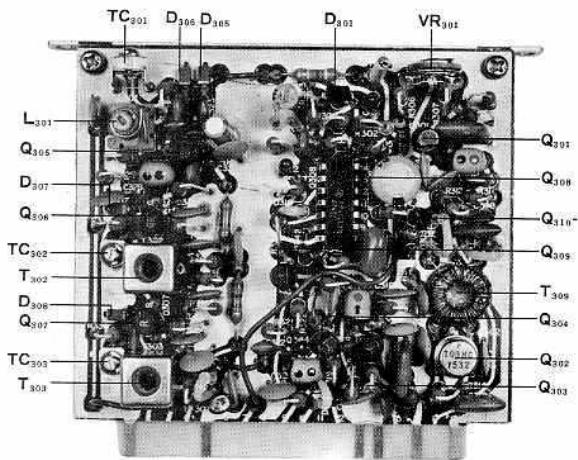


Figure 33

This unit does not require any adjustment unless major components are changed, and, as such, requires precise measuring equipment for alignment. When the PLL circuit is unlocked, the pilot lamps start flikering. Adjust VR₃₀₁ until the circuit locks and the pilot lamps stop flikering. Check that the circuit locks at all segments and entire VFO range.

RX RF UNIT

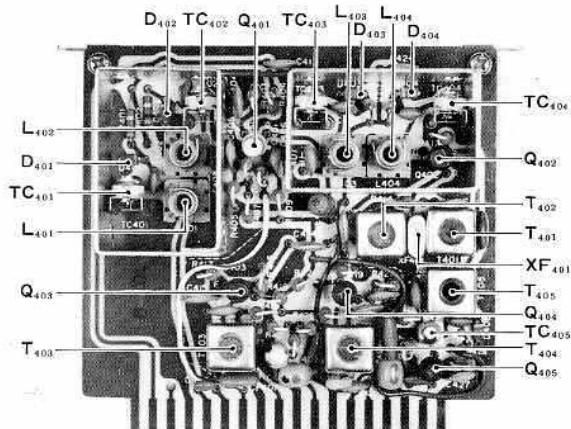


Figure 34

Set the BAND switch to 144.0, the CHANNEL switch to VFO, the RF GAIN control fully clockwise and the MODE switch to the USB mode. Tune the VFO to a signal (144.20 MHz, 10dB) from a signal generator connected to the antenna receptacle. Peak TC₄₀₁, TC₄₀₂, TC₄₀₃ and TC₄₀₄ for a maximum S-meter reading. In areas that use the high side of the band, 146 to 148 MHz, it is recommended to perform above procedures on 146.20 MHz.

EXCITER UNIT/BOOSTER UNIT

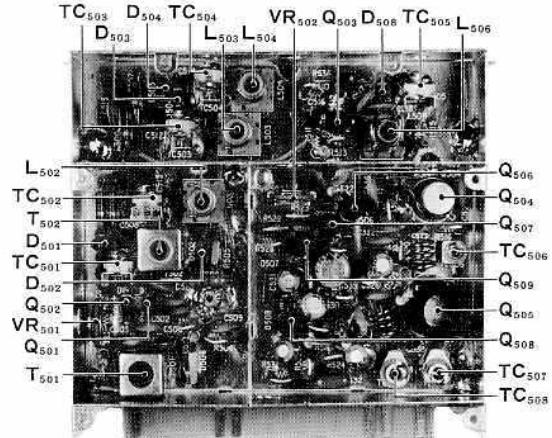


Figure 35

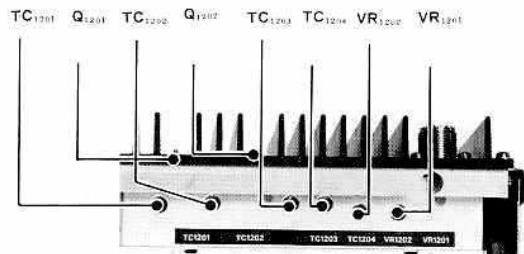


Figure 36

(1) Power Output

It is recommended that an insulated wand be used for the alignment of the booster unit. Connect a dummy load to the antenna receptacle. Set the BAND switch to 145.0, the CHANNEL switch to VFO and the MODE switch to FM. Set the VFO to 145.0 MHz. Set the VOX control to the MOX position. Peak TC₅₀₁ through TC₅₀₈ and TC₁₂₀₁ through TC₁₂₀₄ for maximum power output.

Change the frequency to 144.1 MHz and repeat above procedures for maximum power output. Change the frequency to 147.9 MHz and repeat above procedures for maximum power output.

Repeat the procedures alternately on 144.1 MHz, 145.0 MHz and 147.9 MHz until unity power output is obtained over 144 to 148 MHz.

(2) PO Meter Set

The PO (Power Output) meter indicates relative power output. After the completion of the above power output alignment, set the meter control, VR₁₂₀₂, to the point where the meter indicates 80% of full scale.

(3) AM Carrier Level

Set the MODE switch to the AM position. Adjust VR₅₀₂, in the EXCITER UNIT, for 2.5 watts unmodulated carrier output on the dummy load.

(4) ALC Threshold

Connect the output from a two-tone signal generator to the microphone input and dummy load to the antenna receptacle. Set the BAND switch to 145.0, the CHANNEL switch to VFO, the MODE to USB and the MIC GAIN to the 12 o'clock position. Set the VOX GAIN control to the MOX positoin. Apply a 1 kHz single tone signal at first and adjust the signal generator output until the power meter shows 2.5 watts. Then apply a 1.5 kHz single tone signal and adjust its output for 2.5 watts output. Then leave the output levels of both tones at the set level and apply a 1 kHz/1500 kHz, two tone signal, of the above set level. Adjust VR₁₂₀₁ until the power meter indicates 3 watts.

SQUELCH THRESHOLD

Disconnect the antenna. Set the BAND switch to 144.0, the CHANNEL switch to VFO, the RF GAIN to the fully CW position, the MODE switch to FM and SQUELCH control to the 9 o'clock position. Adjust VR₁₄₀₁ to the point where the receiver is just silenced. Do not go beyond this threshold point or the SQUELCH control on the front panel will not function properly.

FM DEVIATION ADJUSTMENT

Connect a dummy load and an FM deviation meter to the antenna receptacle and audio signal from an audio oscillator to the microphone input. Set the MODE switch to FM mode, MIC GAIN control to an 11 o'clock position, and a VOX control to MOX position. Set VR₁₁₀₁ to a fully clockwise position and VR₁₁₀₄ to the centre of its range.

Apply a 1 kHz 3mV audio signal to the microphone input. Observe wave form in the oscilloscope pattern which is connected to the frequency deviation meter. Adjust VR₁₁₀₄ until sine wave is obtained in the scope pattern.

Connect a frequency counter to Pin 3 of MIC AMP UNIT (J22) and disconnect audio signal input to the microphone. Adjust L₁₁₀₁ until oscillating frequency becomes exactly 10.7 MHz. Connect again the audio signal to the microphone input. Adjust MIC GAIN control for ± 5 kHz deviation with sine wave pattern in the scope. If sine wave pattern is not obtained, repeat above procedures. Increase audio signal input level to 8mV and adjust VR₁₁₀₁ for ± 5 kHz deviation.

TONE BURST UNIT

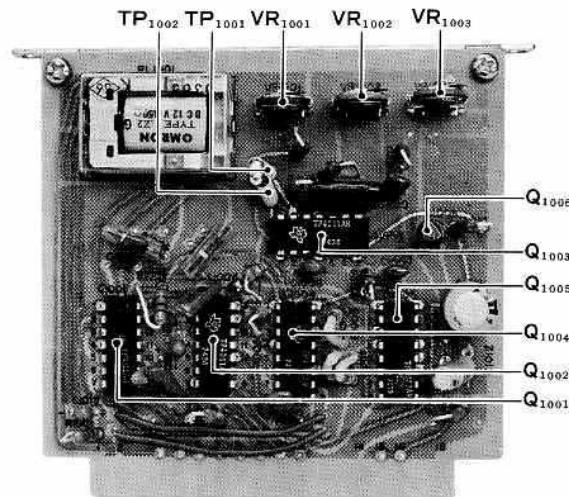


Figure 37

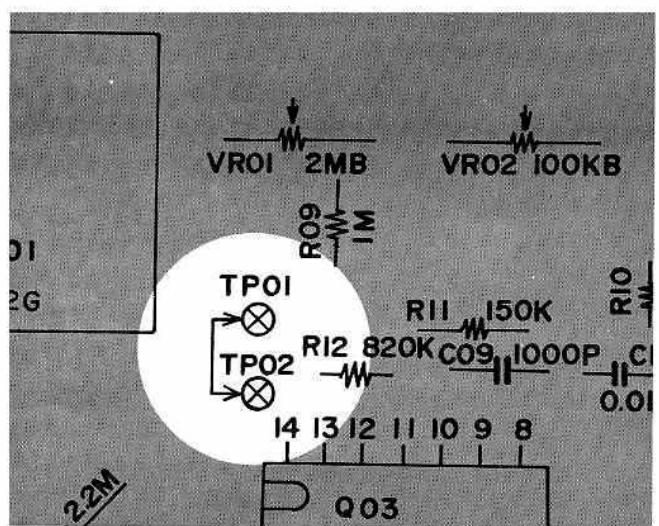


Figure 38

The adjustment of this unit should be done after the above FM deviation alignment has been completed. Set the controls, switches and the deviation meter as described in the deviation adjustment. Remove the tone burst unit from the chassis and disconnect the connection of the two test points as illustrated in order to obtain a continuous tone signal during the alignment. Insert the unit into its socket.

Set the MIC GAIN control to the 2 o'clock position and the VOX GAIN control to the MOX position. Measure the burst tone signal frequency at the deviation meter output. Adjust VR₁₀₀₂ to the desired frequency. Adjust VR₁₀₀₃ for ± 3.5 kHz deviation.

Set the VOX GAIN control to the PTT position and remove the unit from its socket. Reconnect the disconnected test points and reinstall it into its socket.

The burst signal is automatically transmitted when the PTT switch on the microphone is keyed twice as, i.e., key 0.5 second, receive 0.5 second and then transmit. The deviation of the burst signal is preset at the factory to approximately 0.5 second. It may be adjusted with VR₁₀₀₁. A clockwise rotation produces a longer deviation.

REGULATOR UNIT

Use an AC supply for this alignment. Connect a VTVM DC probe to the 13.5 volt line of the power supply unit. Adjust VR₁₅₀ for a 13.5 volt VTVM reading. Connect the VTVM to the 8 volt line and adjust VR₁₅₀₂ for a 8 volt VTVM reading.

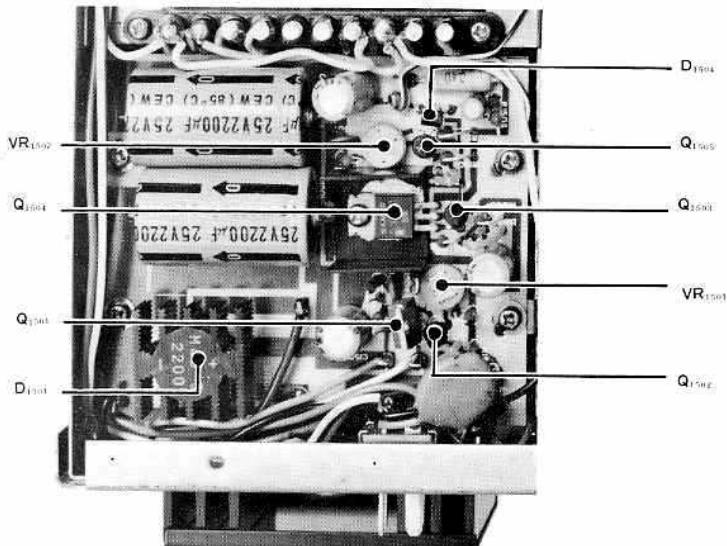


Figure 39

FM IF UNIT

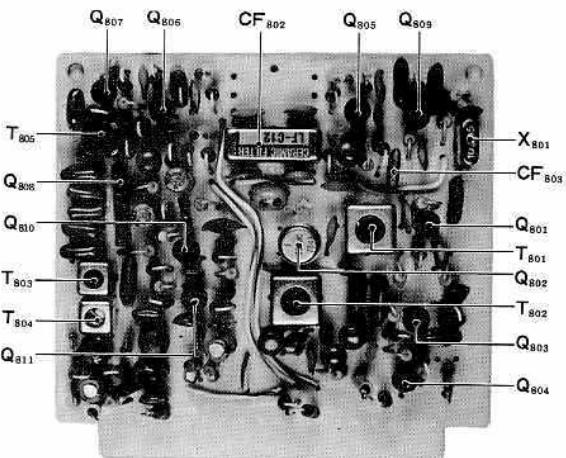
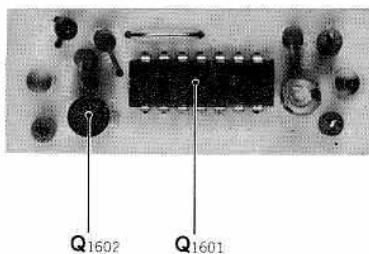


Figure 40



KEYING UNIT (PB-1568)

Figure 41

CONNECTOR RESISTANCE CHART

PIN \ UNIT	FIX	LOCAL	PLL	RX RF	EXCITER	AF AMP	MARKER	FM IF	SSB IF	TONE BURST	MIC AMP
	J ₁₂	J ₁₃	J ₁₄	J ₁₅	J ₁₆	J ₁₇	J ₁₈	J ₁₉	J ₂₀	J ₂₁	J ₂₂
1	E	E	E	E	E	E	E	E	E	E	E
2	∞	E	O	2.6K	250	0	53*	5.5K	E	1.7K	E
3	∞	O	2.3K	—	250	53*	2.4K	E	3.5K	—	6K
4	∞	—	53*	E	O	74*	2.5K	500	—	450	3.2K
5	∞	E	E	O	6K	—	2.5K	10	700	53	300
6	∞	E	45*	∞	E	∞	3K	1K	—	53	E
7	∞	53	160*	O	E	0	3K	300	250	∞	E
8	∞	—	E	E	2.4K	0	3K	1.6K	—	2.4K	O
9	E	E	2K	0	2K	40*	2.7K	E	53*	2.4K	12K
10	E	E	160*	E	2.6K	E	2.3K	2.5K	—	∞	700
11	∞	—	—	53*	2.6K	—	E	E	E	350	E
12	53*	—	53*	E	100K	1.6K	∞	—	—	—	E
13	∞	—	E	2.4K	1.1K	850	E	53*	700K	—	E
14	∞	—	E	3.5K	E	1K	—	3.3K	—	850	700K
15	∞	—	O	3.3K	E	2.1K	—	100 K	250	—	250
16	∞	—	—	E	E	1.5K	2.4K	E	500	—	250
17	∞	—	∞	0	∞	5.5K	E	0	2.6K	—	E
18	E	—	E	E	E	E	E	E	46*	E	E
19		—							—		E
20		—							—		650
21		∞							300		53*
22		54*							—		500
23		—							400		E
24		—							400		E
25		—							∞		9K
26		—							—		O
27		—							53*		9 K
28		—							500		∞
29		—							4.5K		850
30		—							E		2.2K
31		—							E		∞
32		—							500		5K
33		17K							1.9K		∞
34		—							E		1K
35		E							E		E
36		E							E		E

Switch, Knob Position

POWER...OFF MODE...FM BAND...144.0 CHANNEL...VFO RF GAIN...MAX VOX GAIN...PTT

AF GAIN
MIC GAIN
SQUELCH }...CENTER

FUNCTION SW...OFF

Measured with 20KΩ/V

Values are in OHMS

CONNECTOR VOLTAGE CHART

Measured with VTVM.
Values are in VOLTS DC

VOLTAGE CHART

FIX Unit

	E	B	C		E	B	C
Q101	0.9	1.4	7.7	Q102	2.2	2.9	5.8

LOCAL Unit

	E	B	C		E	B	C		E	B	C
Q201	2.4	2.5	7.6	Q202	1.1	1.3	7.9	Q203	0.9	1.4	7.6

PLL Unit

	E(S)	B(G)	C(D)		E(S)	B(G)	C(D)		E(S)	B(G)	C(D)
Q301	1.6	0	4.5	Q305	0.9	0	5.4	Q309	0	0	8.0
Q303	0.9	1.4	8.0	Q306	1.0	0	5.9	Q310	0	0.7	1.3
Q304	0.5	1.1	7.5	Q307	0.5	0.8	7.2				

	1	2	3	4	5	6	7	8	9	10	11	12	13	14
Q302	7.2	—	1.5	E	1.5	—	7.2	7.5						
Q308	4.9	4.9	0.2	8.0	0	1.9	E	8.0	8.0	0	8.0	0	0	8.0

RX RF Unit

	E (S)		B (G)		C (D)		G ₂			E (S)		B (G)		C (D)	
	R	T	R	T	R	T	R	T		R	T	R	T	R	T
Q401	1.5	0	1.6	0	8.0	0.1	3.9	0	Q404	0.7	0	1.4	0	7.9	0.1
Q402	1.6	1.1	0	0	7.9	0.1			Q405	1.0	0	0	0	7.7	0
Q403	1.2	0	1.8	0	7.8	0.1									

EXCITER Unit (on Transmit)

	LSB.USB.CW			AM.FM				LSB.USB.CW			AM.FM									
	E (S)	B (G)	C (D)	E (S)	B (G)	C (D)		E (S)	B (G)	C (D)	E (S)	B (G)	C (D)							
	R	T	R	T	R	T		R	T	R	R	T	R							
Q501	1.3	0	12.1	1.4	0	11.8	Q504	0.4	1.2	10.1	0.4	1.2	10.0	Q507	0	0	13.3	0	0	13.3
Q502	1.3	0	12.1	1.4	0	11.7	Q505	0	0.7	13.4	0	0.7	13.4	Q508	1.1	1.8	5.4	1.1	1.8	5.4
Q503	1.2	1.9	12.0	1.2	1.9	11.9	Q506	12.5	13.3	13.5	12.5	13.3	13.5	Q509	4.9	5.5	13.5	4.9	5.5	13.5

Receive.....0V

AF AMP Unit

	LSB.USB.CW AM			F M				LSB.USB.CW AM			F M				LSB.USB.CW AM			F M		
	E(S)	B(G)	C(D)	E(S)	B(G)	C(D)		E(S)	B(G)	C(D)	E(S)	B(G)	C(D)		E(S)	B(G)	C(D)	E(S)	B(G)	C(D)
Q601	0.4	1.0	7.0	0.4	1.0	7.0	Q607	0	0	0.6	0	0	0.6	Q612	13.5	12.9	7.5	13.5	12.9	7.5
Q603	0.4	0	0.6	0.4	0	0.6	Q608	0	0	0	1.9*	0	5.7*	Q613	6.8	7.4	13.5	6.8	7.4	13.5
Q604	0	0.6	12.9	0	0.6	12.9	Q609	0	0	0	2.6*	0	6.3*	Q614	6.8	6.2	0	6.8	6.2	0
Q605	0.4	1.0	5.8	0.4	1.0	5.8	Q610	0	0.6	3.8	0	0.6	3.8							
Q606	2.9	1.0	8.0	2.9	1.0	8.0	Q611	8.5	9.1	12.9	8.5	9.1	12.9							

* FM Transmit.....0V

	1	2	3	4	5	6	7	8	9
	Q602	4.7	2.8	2.2	2.1	0	0.5	0.7	1.1

MARKER Unit (Marker Switch.....ON)

	E	B	C				E	B	C				E	B	C
	Q701	1.8	2.4	8.0	Q702	2.1	3.7	7.7	Q704	E	0.6	0.9			

	1	2	3	4	5	6	7	8	9	10	11	12	13	14
	Q703	1.8	E	3.8	4.0	4.0	4.0	E	0	4.0	0	3.7	3.0	0

FM Unit

	LSB.USB.CW AM			F M				LSB.USB.CW AM			F M				LSB.USB.CW AM			F M		
	E(S)	B(G)	C(D)	E(S)	B(G)	C(D)		E(S)	B(G)	C(D)	E(S)	B(G)	C(D)		E(S)	B(G)	C(D)	E(S)	B(G)	C(D)
Q801	1.8	2.5	7.7	1.8	2.5	7.7	Q805	0	0	0	1.3*	0.7	7.2*	Q809	0	0	0	0.6*	1.3*	7.0*
Q803	0	1.9	5.1	0	1.9	5.1	Q806	0	0	0	1.4*	2.1	2.5*							
Q804	5.8	5.8	5.3	5.8	5.8	5.3	Q807	0	0	0	0.7*	1.4	7.0*							

* FM Transmit.....0V

		1	2	3	4	5	6	7	8
		T · R	7.0	—	1.5	0	1.5	—	7.0

Q808	FM · R	1.8	1.8	6.8	0	5.5	1.8	1.8	
	T · R	0	0	0	0	0	0	0	

SSB IF Unit

	E(S)		B(G)		C(D)			E(S)		B(G)		C(D)			E(S)		B(G)		C(D)	
	R	T	R	T	R	T		R	T	R	T	R	T		R	T	R	T	R	T
Q901	0.7	0	0.7	0	7.3	0	Q905	0	0	0.7	0	7.2	0	Q908	0.3	0.3	1.0	1.0	5.8	5.8
Q903	1.1	0	0	0	7.8	0	Q906	0	0.6	0	0	0	7.0							
Q904	0.7	0	0.7	0	7.3	0	Q907	5.3	5.3	5.9	5.9	6.8	6.8							

		1	2	3	4	5	6	7	8
Q902	R	0	1.2	0	1.8	5.5	7.6	7.3	0
	T	0	0	0	0	0	0	0	0

TONE BURST Unit

		1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
Q1001	R	0	0	8.0	0	8.0	8.0	0	0	0	8.0	0	8.0	7.2	8.0		
	T	8.0	8.0	0	8.0	0	0	0	0	0	8.0	0	8.0	7.2	8.0		
Q1002	R · T	7.2	8.0	0	8.0	0	0	0	0	8.0	8.0	8.0	0	0	8.0		
Q1003	R · T	0	0	8.0	0	8.0	7.3	0	8.0	8.0	0	8.0	7.2	0	8.0		
Q1004	R	8.0	0	7.2	0	7.3	0	8.0	0	0	8.0	8.0	0	0	7.2	0	8.0
	T	8.0	0	7.2	0	7.3	0	8.0	0	8.0	0	8.0	0	0	7.3	0	8.0
Q1005	R · T	0	8.0	0	0	8.0	8.0	0	0	0	0	0	0	0	8.0	0	8.0

	S	G	D
Q1006	0.9	0	8.0

BOOSTER Unit (on Transmit)

	LSB.USB.CW			AM			FM				LSB.USB.CW			AM			FM		
	E(S)	B(G)	C(D)	E(S)	B(G)	C(D)	E(S)	B(G)	C(D)		E(S)	B(G)	C(D)	E(S)	B(G)	C(D)	E(S)	B(G)	C(D)
Q1201	0	0.7	12.3	0	0.6	3.6	0	0.6	11.7	Q1202	0	0.7	13.5	0	0.4	13.3	0	0.2	13.1

Receive.....0V

VFO Unit

	E(S)	B(G)	C(D)		E(S)	B(G)	C(D)		E(S)	B(G)	C(D)
Q1301	2.1	2.7	4.4	Q1302	1.6	0	7.6	Q1303	1.6	2.1	6.9

MIC AMP Unit

\	L S B. U S B						C W						A M						F M					
	E(S)		B(G)		C(D)		E(S)		B(G)		C(D)		E(S)		B(G)		C(D)		E(S)		B(G)		C(D)	
	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T	R	T
Q1101	0	0	0	0	0	0	0	4.9	0	2.6	0	8.0	0	1.9	0	2.6	0	7.8	0	2.2	0	2.6	0	7.8
Q1102	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	1.6	0	2.2	0	7.2
Q1103	1.5	1.5	2.1	2.1	3.9	3.9	1.5	1.5	2.1	2.1	3.9	3.9	1.5	1.5	2.1	2.1	3.9	3.9	1.5	1.5	2.1	2.1	3.9	3.9
Q1105	0	2.2	0	0	0	7.8	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Q1106	0	0.7	0	0	0	7.3	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
Q1107	3.0	3.0	3.4	3.4	6.8	6.8	3.0	4.9	3.4	3.4	6.8	8.0	2.7	3.0	3.4	3.4	6.8	6.7	2.7	2.7	3.4	3.4	6.8	6.8
Q1108	2.5	2.5	1.9	1.9	6.8	6.8	2.5	2.5	2.1	2.3	6.8	6.8	2.3	2.5	1.4	1.8	6.9	6.8	2.3	2.3	1.3	1.4	6.9	6.9
Q1109	1.3	1.3	0	0	6.9	6.9	1.3	1.3	0	0	6.9	6.9	1.3	1.3	0	0	6.9	6.9	1.3	1.3	0	0	6.9	6.9
Q1110	4.7	4.7	5.4	5.4	6.9	6.9	4.7	4.7	5.4	5.4	6.9	6.9	4.7	4.7	5.4	5.4	6.9	6.9	4.7	4.7	5.4	5.4	6.9	6.9

\	1	2	3	4	5	6	7	8	9
		R	4.1	2.4	1.8	1.7	0	0	0.7
	T	4.1	2.4	1.8	1.7	0	0.5	3.3	1.2

REG Unit

\	E	B	C	\	E	B	C	\	E	B	C
	R	T	R		R	T	R		R	T	R
Q1501	14.1	14.6	22.6	Q1503	8.7	9.3	13.5	Q1505	6.1	6.7	9.3
Q1502	9.0	9.7	14.6	Q1504	8.0	13.5	8.7	Q1	13.5	14.1	22.5

AM Mod(Q7)

\	E		B		C	
	R	T	R	T	R	T
U S B U S B C W	0	12.3	0	12.9	0	13.5
AM	0	3.6	0	4.2	0	13.4
FM	0	11.7	0	12.3	0	13.2

PARTS LIST

MAIN CHASSIS			6, 7	SLE-12251
PB PRINTED CIRCUIT BOARD			8	SLE-14201
1471 (A~Z) LED BOARD			9	SLE-14301
1552 (A~Z) SWITCH BOARD			J JACK	
Q TRANSISTOR			1	QMS-AB4M
1 2SD114			2	CS-250
7 2SD313D			3	SG-7615
D DIODE			4	SG-8050
1 Si DS-130-YD			5	FM-144J
6~10 Si 10D-1			6	XG-8018
11 LED GD-4			7~10	CN-7017J
12 " RD-4			11	SO-239
13 " TLR-108			12, 14~19, 21	3305-018-011
R RESISTOR			13, 20, 22	1150-036-009
CARBON COMPOSITION			25	CN-1463
16 $\frac{1}{4}$ W 10KΩ			24	SI-8503
15 $\frac{1}{4}$ W 100KΩ			P PLUG	
19 $\frac{1}{2}$ W 10Ω			24	SI-8501
17 $\frac{1}{2}$ W 56Ω				
18 $\frac{1}{2}$ W 100Ω			F FUSE	
14, $\frac{1}{2}$ W 220Ω			1	2A 100V~117V
13, 21 $\frac{1}{2}$ W 470Ω				1A 200V~234V
23 $\frac{1}{2}$ W 5.6KΩ				
11 $\frac{1}{2}$ W 22KΩ			FS FUSE HOLDER	
12 $\frac{1}{2}$ W 27KΩ			1	SN-1001 #2
VR POTENTIOMETER				
4 EWK-DOAS 15023 500ΩB/500ΩC			PL PILOT LAMP	
5 VM13A-5M3121 5KA			1~3	14V 40mA
8 EVH-BOAS-15A53 5KA				
6 VM20A 5KB				
7 VM11A5M 10KA				
			FIX UNIT	
			PB PRINTED CIRCUIT BOARD	
3 EVH-BOAS-15B54 50KB			1453 (A~Z) FIX OSC CIRCUIT	
10 EVH-BOAS-15B53 5KB			1500 (A~Z) CRYSTAL BOARD	
C CAPACITOR				
DIPPED MICA			Q TRANSISTOR	
16, 17, 18 50WV 100PF			101, 102	2SC372Y
22 50WV 300PF				
CERAMIC DISC			D DIODE	
14, 28~32 50WV 0.001μF			101~111	Si 1S1555
13, 33~35 50WV 0.01μF				
11, 12, 15, 19~21, 23, 27 50WV 0.047μF			X CRYSTAL	
24~26 500WV 0.01μF			101~111	HC-25/U (OPTION)
1, 2 1.4KV 0.0047μF				
ELECTROLYTIC			XS CRYSTAL SOCKET	
10 16WV 2200μF			101~111	S2-101P
PT POWER TRANSFORMER				
1 52-36			R RESISTOR	
CH CHOKE COIL			CARBON FILM	
1 SN-8S-500			105, 108, 109	$\frac{1}{4}$ W 100Ω
L INDUCTOR			104	$\frac{1}{4}$ W 220Ω
1 RFC 250μH			101	$\frac{1}{4}$ W 1.5KΩ
M METER			102, 107, 110	$\frac{1}{4}$ W 5.6KΩ
1 SP-38A			106	$\frac{1}{4}$ W 8.2KΩ
			103	$\frac{1}{4}$ W 22KΩ
SP SPEAKER			C CAPACITOR	
1 SA-70H			DIPPED MICA	
RL RELAY			130	50WV 15PF
1 AE-3171			131	50WV 20PF
			117~127	50WV 30PF
RLS RELAY SOCKET			129	50WV 100PF
1 AE-3860			128, 132	50WV 200PF
				CERAMIC DISC
S SWITCH			101~116	50WV 0.01μF
1 ESR-E22CR15D				
2 ESR-448R15A			TC TRIMMER CAPACITOR	
3 ESR-485R15A			101~111	ECV-1ZW 20×40 20PF
4 SP-2022				
5 SLE-12301			L INDUCTOR	

101~111	EL0610-102K	1mH	PLL UNIT					
112	EL0610-251K	250μH	PB PRINTED CIRCUIT BOARD					
113	FL-3H 1R2M	1.2μH	1455 (A~Z) PLL CIRCUIT					
Q IC FET & TRANSISTOR								
LOCAL UNIT			302	IC	μA703HC			
PB PRINTED CIRCUIT BOARD			308	"	TP4011AN			
1454 (A~Z) LOCAL OSC CIRCUIT			301	FET	2SK19Y			
			305, 306	"	2SK19GR			
Q TRANSISTOR			303, 304, 309	Tr	2SC372Y			
201	2SC372Y		307	"	2SC784R			
202, 203	2SC784R		310	"	MPSA13			
D DIODE								
201~212 Si 1S1555			301	PUT	N13T1			
225 Ge	1S188FM		309, 310	Si	1S1555			
226 Varactor	1SV50		311	Ge	1S188FM			
			303, 304	"	1S1007			
			302	Zener	WZ061			
X CRYSTAL			305, 306	Varactor	1SV50			
201 HC-18/U	13.92222MHz		307, 308	Varactor	1S2209			
202 "	13.97777MHz		R RESISTOR					
203 "	14.03333MHz		CARBON FILM					
204 "	14.08888MHz		305	1/4W	22Ω			
205 "	14.14444MHz		337	1/4W	56Ω			
206 "	14.20000MHz		313, 315, 319, 320, 329, 333, 334	1/4W	100Ω			
207 "	14.25555MHz		303	1/4W	150Ω			
208 "	14.31111MHz		304, 308, 314, 326, 328	1/4W	220Ω			
210 (Repeater) HC-25/U ★(14.13333MHz)			325	1/4W	270Ω			
211 (Repeater) "	★(14.32222MHz)		307	1/4W	330Ω			
★US Model ★★European Model ★★(14.02222MHz)			310, 316,	1/4W	1KΩ			
XS CRYSTAL SOCKET			302, 345, 346	1/4W	2.2KΩ			
201 S-14			317, 321, 330	1/4W	4.7KΩ			
			311, 312	1/4W	10KΩ			
R RESISTOR			306, 318, 322, 331	1/4W	22KΩ			
CARBON FILM			301	1/4W	47KΩ			
221, 225 1/4W	100Ω		309, 323, 324, 327, 340, 344	1/4W	100KΩ			
217, 224 1/4W	220Ω		339	1/4W	560KΩ			
220 1/4W	560Ω		332, 336, 338, 341, 343	1/4W	1MΩ			
213, 216, 226 1/4W	1KΩ		C CARBON COMPOSITION					
222 1/4W	2.2KΩ		342	1/4W	2.2MΩ			
201~212 1/4W	3.3KΩ		RS THERMISTOR					
215, 218 1/4W	4.7KΩ		301	SDT-250				
214, 223 1/4W	10KΩ		VR POTENTIOMETER					
219 1/4W	22KΩ		301	KVL-SOAA-00B13	1KB			
C CAPACITOR								
DIPPED MICA								
242 50WV	1PF		322, 327	50WV	5PF			
239 50WV	5PF		339, 340	50WV	6PF			
240, 241 50WV	8PF		318, 319	50WV	10PF			
213~224, 236, 238 50WV	30PF		308, 309	50WV	20PF			
237 50WV	39PF		325, 326	50WV	30PF			
234 50WV	150PF		323, 324	50WV	47PF			
235 50WV	200PF		305, 312, 313	50WV	170PF			
CERAMIC DISC			307	50WV	200PF			
201~212, 225~230, 232, 233 50WV	0.01μF		CERAMIC DISC					
231, 243 50WV	0.047μF		304, 306, 310, 311, 314~317	50WV	0.01μF			
320, 321, 328, 329, 331~336, 344, 345, 338								
TC TRIMMER CAPACITOR								
201~212 ECV-1ZW 20×40	20PF		341	50WV	0.01μF			
343			343	50WV	0.1μF			
L INDUCTOR								
203 # 221026	3.2μH		301, 342	35WV	0.1μF			
202, 204, 201 EL0610-220K	22μH		MYLAR					
ELECTROLYTIC								
303, 330			303, 330	16WV	10μF			
302			302	16WV	100μF			
T TRANSFORMER								
201 R-12 # 4797								
202, 203 R-12 # 4102								

TC	TRIMMER CAPACITOR		404, 414, 417	50WV	0.001μF
301	ECV-1ZW 10×40	10PF	405~407, 412, 413,	50WV	0.01μF
302, 303	ECV-1ZW 10×51	10PF	418~420, 424, 425, 427, 428,		
			415, 416	50WV	0.047μF
L	INDUCTOR			ELECTROLYTIC	
302	FL-3H-3R3M	3.3μH	423	16WV	1μF
304, 306	RFC	10μH	TC	TRIMMER CAPACITOR	
303, 305	RFC	250μH	401~404	ECV-1ZW 10×40	10PF
301	OSC #221013A		405	ECV-1ZW 10×53	10PF
T	TRANSFORMER		L	INDUCTOR	
309	#221014		401	#221003	
302, 303	R-12 4102		402	#221004	
			403	#221005	
			404	#221006	
			406	EL0610-220K	22μH
			407, 408	EL0610-251K	250μH
			405	EL0610-102K	1mH
T	TRANSFORMER				
			401~404	R-12 4074	
			405	R-12 4102	
				EXCITER UNIT	
PB	PRINTED CIRCUIT BOARD		PB	PRINTED CIRCUIT BOARD	
1456 (A~Z)	RX RF CIRCUIT		1466 (A~Z)	EXCITER CIRCUIT	
Q	FET & TRANSISTOR		Q	FET & TRANSISTOR	
401	FET	3SK51(3SK40M)	501, 502	FET	2SK19GR
402, 405	"	2SK19GR	507, 509		2SC372Y
403, 404		2SC372Y	508		2SC373
			505		2SC730
			506		2SC735Y
D	DIODE		504		2SC741
407	G.B	1S1007	503		2SC784R
401~404, 408	Varactor	1S2209			
XF	CRYSTAL FILTER		D	DIODE	
401	FMT-30		505~507	Si	1S1555
			501~504, 508	Varactor	1S2209
R	RESISTOR		R	RESISTOR	
				CARBON FILM	
R	RESISTOR		516	½W	10Ω
			520, 532	½W	56Ω
			509, 513, 531	½W	100Ω
408, 414, 418, 422, 429	½W	100Ω	512	½W	220Ω
428	½W	220Ω	515	½W	330Ω
417, 421	½W	470Ω	526	½W	470Ω
413	½W	1KΩ	522	½W	820Ω
409, 426	½W	1.5KΩ	535	½W	1KΩ
423	½W	2.2KΩ	519, 523, 527, 530	½W	2.2KΩ
425	½W	3.9KΩ	508, 510	½W	3.3KΩ
415, 419	½W	4.7KΩ	533, 514	½W	4.7KΩ
416	½W	15KΩ	524	½W	5.6KΩ
405, 420	½W	22KΩ	529	½W	10KΩ
403, 404, 406, 407, 427	½W	100KΩ	511, 528	½W	15KΩ
			525	½W	27KΩ
			501, 502	½W	47KΩ
C	CAPACITOR			CARBON COMPOSITION	
	DIPPED MICA		503~507, 536	½W	1MΩ
422	50WV	1PF	534	½W	10Ω
401, 402, 408, 409	50WV	5PF			
429	50WV	6PF	VR	POTENTIOMETER	
403	50WV	30PF	501	EVL-SOAA-00B13	1KB
426	50WV	47PF	502	EVL-SOAA-00B54	50KB
411	50WV	100PF	C	CAPACITOR	
421	50WV	180PF		DIPPED MICA	
	CERAMIC DISC				

511, 512, 514, 519	50WV	5PF	634, 613	1/4W	47KΩ
507, 508, 516, 523, 537, 538	50WV	10PF	603, 633, 637	1/4W	100KΩ
510, 506, 535	50WV	20PF	607	1/4W	1MΩ
528	50WV	39PF			
CERAMIC DISC		CARBON COMPOSITION			
513, 534	50WV	1PF	608, 609	1/2W	3.3MΩ
502, 503	50WV	0.001μF	610	1/2W	5.6MΩ
501, 504, 505, 509, 515,	50WV	0.01μF		WIRE WOUND	
517, 518, 520 ~ 522, 524, 526, 536, 539			645, 646	1/2W	0.22Ω
MYLAR					
532	50WV	0.047μF	RS THERMISTOR		
ELECTROLYTIC		601	SDT-250		
525, 527, 529, 531	16WV	10μF			
530	16WV	22μF	VR POTENTIOMETER		
533		33μF	605	EVL-SOAA-00B53	5KB
TC TRIMMER CAPACITOR		602, 603	EVL-VOAA-00B14	10KB	
501 ~ 505	ECV-1ZW 10×40	10PF	604	EVL-SOAA-00B14	10KB
506	ECV-1ZW 20×51	20PF	606	EVL-SOAA-00B54	50KB
507, 508	ECV-1ZW 20×32	20PF	601	EVL-VOAA-00B26	2MB
C CAPACITOR					
L INDUCTOR			DIPPED MICA		
503	# 221008		637	50WV	200PF
504, 502	# 221009		635	50WV	280PF
507, 510	# 221018		628	50WV	330PF
508, 509	# 221017		605	CERAMIC DISC	
506	# 221036		636	50WV	470PF
				50WV	0.047μF
T TRANSFORMER			MYLAR		
501	R-12 4073		610, 615	50WV	0.001μF
502	# 221035		629, 630	50WV	0.002μF
			608, 611, 619, 620	50WV	0.01μF
			616 ~ 618	50WV	0.02μF
AF UNIT			614, 631	50WV	0.047μF
PB PRINTED CIRCUIT BOARD			609	50WV	0.1μF
1499 (A ~ Z) AF CIRCUIT				ELECTROLYTIC	
Q IC FET & TRANSISTOR			601, 612, 623, 626	16WV	1μF
602	IC LD 3001		621, 622	16WV	4.7μF
603	FET 2SK19Y		602 ~ 604, 606, 607, 613	16WV	10μF
608, 609	" 2SK19GR		624	10WV	100μF
612	2SA695		625, 633	16WV	100μF
614	2SB529		627, 632	16WV	220μF
601, 605, 606, 607, 610	2SC372Y				
611	2SC711		MARKER UNIT		
604	2SC735Y		PB PRINTED CIRCUIT BOARD		
613	2SD359		1459 (A ~ Z) MARKER CIRCUIT		
D DIODE			Q IC & TRANSISTOR		
601 ~ 604	Si 1S1555		703	IC 34024PC	
605	Varistor MV-5W		701, 702, 704	Tr 2SC372Y	
R RESISTOR			X CRYSTAL		
CARBON FILM			701	HC-18/U 12.8MHz	
642	1/4W	10Ω			
641	1/4W	22Ω	R RESISTOR		
628	1/4W	100Ω	CARBON FILM		
647	1/4W	180Ω	701 ~ 708	1/4W	100Ω
622, 629, 644	1/4W	220Ω	711, 713	1/4W	1KΩ
626	1/4W	470Ω	716	1/4W	2.2KΩ
611	1/4W	680Ω	710	1/4W	10KΩ
601, 616, 638, 639	1/4W	1KΩ	709, 715	1/4W	22KΩ
604, 635, 636	1/4W	1.5KΩ	714	1/4W	100KΩ
623, 624, 625, 631	1/4W	2.2KΩ	712	1/4W	220KΩ
605, 614, 643	1/4W	3.3KΩ			
606, 612, 618, 619, 620, 627	1/4W	4.7KΩ	VR POTENTIOMETER		
617	1/4W	5.6KΩ	701 ~ 708	EVL-SOAA-OOB14	10KB
630, 632	1/4W	6.8KΩ	C CAPACITOR		
602	1/4W	15KΩ	DIPPED MICA		
615	1/4W	22KΩ	709	50WV	3PF
621	1/4W	33KΩ	701, 707	50WV	27PF
640	1/4W	39KΩ	702, 703	50WV	220PF

CERAMIC DISC			810, 830, 831, 837, 838, 841	50WV	0.01 μ F
704~706, 708			50WV	0.01 μ F	0.02 μ F
			828, 829	50WV	0.02 μ F
			811, 817, 818, 820~825	50WV	0.047 μ F
ELECTROLYTIC			STYROL		
710			826	50WV	330PF
			827	50WV	1000PF
TC TRIMMER CAPACITOR			TANTALUM		
701			839, 840	25WV	1 μ F
L INDUCTOR			ELECTROLYTIC		
702			849, 850	16WV	1 μ F
701			832, 842	16WV	4.7 μ F
FM IF UNIT			L INDUCTOR		
PB PRINTED CIRCUIT BOARD			804	EL0610-251K	250 μ H
1463 (A~Z) FM IF CIRCUIT			801~803, 806, 807	EL0610-102K	1mH
			805	EL0610-202K	2mH
Q IC FET & TRANSISTOR			T TRANSFORMER		
802			801, 802	R-12	4074
808			803		4861D
803			804		4861E
801, 804~807, 809~811			805		3004
D DIODE			SSB IF UNIT		
801, 802, 807~810			PB PRINTED CIRCVIT BOARD		
803~806			1462 (A~Z) SSB IF CIRCUIT		
X CRYSTAL			Q IC FET & TRANSISTOR		
801			902	IC	TA7045M
CF CERAMIC FILTER			903, 906	FET	2SK19GR
802			904, 905		2SC373
803			901		2SC784R
R RESISTOR			907, 908		2SC1000GR
CARBON			D DIODE		
804, 805, 826			901~903, 912, 913	Si	1S1555
825, 827, 837			910	Ge	1S188FM
824			904~907, 909	G.B	1S1007
803, 833, 842			911	Zener	WZ110
808, 816, 819, 828, 829, 836, 846, 847			914	Si	1S1941
809			XF CRYSTAL FILTER		
839, 840			901		XF-10A
811, 813, 814, 821, 843, 849~856			R RESISTOR		
801, 830, 831, 835, 844			CARBON FILM		
822, 838			909, 912, 914, 915, 919,	$\frac{1}{4}$ W	100 Ω
802			932, 933, 939, 940		
815, 845			926, 928	$\frac{1}{4}$ W	270 Ω
823, 834, 841			917, 944, 922	$\frac{1}{4}$ W	470 Ω
820, 832			901, 902, 927	$\frac{1}{4}$ W	560 Ω
848			934, 938, 946, 947, 905	$\frac{1}{4}$ W	1K Ω
806, 807, 810			911, 913, 921		
			908, 910, 918, 930, 945, 924	$\frac{1}{4}$ W	2.2K Ω
RS THERMISTOR			925	$\frac{1}{4}$ W	2.7K Ω
801			903, 904, 942	$\frac{1}{4}$ W	3.3K Ω
			929	$\frac{1}{4}$ W	3.9K Ω
C CAPACITOR			935, 936	$\frac{1}{4}$ W	4.7K Ω
DIPPED MICA			906	$\frac{1}{4}$ W	6.8K Ω
812			941	$\frac{1}{4}$ W	10K Ω
806, 807			920, 943	$\frac{1}{4}$ W	22K Ω
833			907	$\frac{1}{4}$ W	27K Ω
809, 835, 843			937	$\frac{1}{4}$ W	56K Ω
801			916, 931	$\frac{1}{4}$ W	100K Ω
834			923	$\frac{1}{4}$ W	470K Ω
CERAMIC DISC			RS THERMISTOR		
844			901		SDT-250
802~805, 808, 813, 815, 816, 819, 836, 845~848			MYLAR		

VR	POTENTIOMETER		1012	16WV	1μF	
901	EVL-SOAA-00B52	500B	1013	16WV	4.7μF	
903	EVL-SOAA-00B13	1KB	1011	16WV	100μF	
902	EVL-SOAA-00B53	5KB				
C	CAPACITOR		RL	RELAY		
	DIPPED MICA		1001	LZ-2G		
915	50WV	10PF				
912	50WV	20PF				
916	50WV	100PF				
CERAMIC DISC				MIC AMP UNIT		
901, 902, 909~911, 906	50WV	0.01μF		PB	PRINTED CIRCUIT BOARD	
917, 918, 920, 923~929, 933				1460 (A~Z)	MIC AMP CIRCUIT	
903~905, 907, 908, 913, 914	50WV	0.047μF		Q	IC, FET & TRANSISTOR	
	MYLAR			1104	IC LD3001	
932	50WV	0.0047μF		1105, 1106, 1109	FET 2SK19GR	
936, 940, 921	50WV	0.02μF		1101~1103, 1107, 1108, 1110	Tr 2SC372Y	
931, 937	50WV	0.047μF		D	DIODE	
ELECTROLYTIC				1105, 1106, 1112~1114	Si 1S1555	
930, 939	16WV	1μF		1103, 1104	Ge 1S188FM	
938	16WV	10μF		1108~1111	G. B 1S1007	
934, 935, 922	16WV	47μF		1102	Varactor FC63	
				1101	Varistor MV103	
TC	TRIMMER CAPACITOR			X	CRYSTAL	
901	ECV-1ZW 50×40	50PF		1101	HC-18/U 10.7000MHz	
L	INDUCTOR			1102	" 10.7015MHz	
901	EL0610-251K	250μH		1103	" 10.6985MHz	
T	TRANSFORMER			1104	" 10.6993MHz	
901, 902	R-12	4074		R	RESISTOR	
903	R-12	4073		CARBON FILM		
TONE BURST UNIT				1101, 1105, 1112, 1121, 1124	1/4 W 100Ω	
PB	PRINTED CIRCUIT BOARD			1129, 1131, 1132, 1141, 1148~1153		
1461 (A~Z)	TONE BURST CIRCUIT			1152, 1153		
Q	IC & FET			1135~1138, 1142	1/4 W 220Ω	
1001~1003	IC	TP4011AN		1102, 1114	1/4 W 470Ω	
1005		TP4027AN		1155	1/4 W 560Ω	
1004		TP4049AN		1159	1/4 W 820Ω	
1006	FET	2SK19GR		1106, 1113, 1125, 1127, 1145	1/4 W 1KΩ	
				1154, 1156		
				1122, 1123, 1147	1/4 W 2.2KΩ	
D	DIODE			1109	1/4 W 2.7KΩ	
1001~1003	Ge	1S188FM		1104, 1128, 1157, 1158	1/4 W 3.3KΩ	
R	RESISTOR			1146	1/4 W 3.9KΩ	
CARBON FILM				1118, 1120, 1133, 1143	1/4 W 4.7KΩ	
1014	1/4 W	220Ω		1116, 1134, 1140, 1144, 1151	1/4 W 5.6KΩ	
1015	1/4 W	5.6KΩ		1139	1/4 W 6.8KΩ	
1013	1/4 W	10KΩ		1108, 1110, 1117	1/4 W 10KΩ	
1011	1/4 W	180KΩ		1115	1/4 W 12KΩ	
1012	1/4 W	820KΩ		1107, 1111	1/4 W 22KΩ	
1001~1005, 1008~1010	1/4 W	1MΩ		1103	1/4 W 27KΩ	
				1161	1/4 W 56KΩ	
CARBON COMPOSITION				1119	1/4 W 68KΩ	
1006, 1007	1/4 W	2.2MΩ		1126, 1130	1/4 W 100KΩ	
VR	POTENTIOMETER			VR	POTENTIOMETER	
1002, 1003	EVL-SOAA-00B15	100KB		1102	EVL-SOAA 00B32 300B	
1001	EVL-SOAA-00B26	2MB		1103, 1105	EVL-SOAA 00B13 1KB	
C	CAPACITOR			1104	EVL-SOAA 00B23 2KB	
	DIPPED MICA			1101	EVL-SOAA 00B54 50KB	
1009	50WV	1000PF		C	CAPACITOR	
	MYLAR			DIPPED MICA		
1001, 1002, 1004, 1005,	50WV	0.01μF		1106	50WV 15PF	
1007, 1010				1107, 1108, 1147	50WV 100PF	
	TANTALUM			1148	50WV 150PF	
1003	35WV	0.33μF		1110	50WV 750PF	
1006, 1008	35WV	0.47μF				
	ELECTROLYTIC					

CERAMIC DISC			C CAPACITOR		
1159	50WV	3PF	1216	DIPPED MICA	
1133	50WV	10PF	1217, 1223	50WV	2PF
1158	50WV	15PF	1201	50WV	5PF
1146	50WV	22PF	1224	50WV	10PF
1140, 1154~1156	50WV	33PF(CH)	1227	50WV	12PF
1126~1128, 1143	50WV	220PF	1213~1215	50WV	15PF
1136	50WV	0.001μF	1205	50WV	20PF
1101, 1102, 1104, 1134	50WV	0.01μF	1212	50WV	33PF
1135, 1138, 1139, 1141, 1142			1211	50WV	39PF
1144, 1145, 1149~1153			1206	50WV	68PF
1109	50WV	0.047μF			100PF
MYLAR			CERAMIC DISC		
1116		0.0033μF	1202, 1204, 1208, 1210	50WV	0.001μF
1103		0.0047μF	1218~1220	50WV	0.01μF
1115, 1122, 1130, 1132		0.022 μF	1221	50WV	0.001μF
ELECTROLYTIC			TANTALUM		
1117, 1129, 1131	16WV	1μF	1222	35WV	0.1μF
1114, 1118, 1119, 1121	16WV	10μF	1203, 1207, 1209	16WV	10μF
1123~1125, 1137			TC TRIMMER CAPACITOR		
1120	16WV	22μF	1201	ECV-1ZW 50×40	50PF
1112, 1113	16WV	47μF	1202~1204	TSN-P-100DS	20PF
TANTALUM			L INDUCTOR		
1111	35WV	0.1μF	1201, 1207	# 221019	
TC TRIMMER CAPACITOR			1204, 1206, 1208, 1209	# 221020	
1102~1104	ECV-1ZW 20×40	20PF	1211, 1212	# 221021	
1101	ECV-1ZW 50×40	50PF	1202, 1203	# 221022	
L INDUCTOR			1205	# 221037	
1101		# 221024	1210	EL0610-220K	22μH
1107	RFC	10μH	RL RELAY		
1108~1111	RFC	1mH	1201	LZ-2G	DC12 450Ω
T TRANSFORMER			VFO UNIT		
1101	R12-4074		PB PRINTED CIRCUIT BOARD		
1102	R12-4073		1465 (A~Z) VFO CIRCUIT		
BOOSTER UNIT			Q FET & TRANSISTOR		
PB PRINTED CIRCUIT BOARD			1302	FET	2SK19GR
1470 (A~Z) BOOSTER CIRCUIT			1301, 1303		2SC372Y
Q TRANSISTOR			R RESISTOR		
1201	2N5590		R RESISTOR		
1202	2N5591		CARBON FILM		
D DIODE			1307, 1311, 1312	1/4W	100Ω
1201, 1202	Si	10D-1	1310	1/4W	150Ω
1203, 1205~1208		1S1555	1306	1/4W	470Ω
1204	Ge	1S188FM	1304	1/4W	2.2KΩ
1209	Zener	1N4740	1301	1/4W	3.3KΩ
R RESISTOR			1308	1/4W	6.8KΩ
CARBON COMPOSITION			1309	1/4W	15KΩ
1204	1/2W	10Ω	1302	1/4W	18KΩ
1201	1/2W	22Ω	1303	1/4W	33KΩ
1203	1/2W	56Ω	1305	1/4W	100KΩ
1205	1/2W	100Ω	C CAPACITOR		
1202	1/2W	330Ω	DIPPED MICA		
1206	1/2W	100KΩ	1318	50WV	2PF
1207	1/2W	1MΩ	1302	50WV	20PF
VR POTENTIOMETER			1313	50WV	39PF
1201	EVL-SOAA-00B14	10KB	1306	50WV	51PF
1202	EVL-SOAA-00B54	50KB	1311	50WV	68PF
			1307	50WV	270PF
			1310	50WV	470PF

CERAMIC DISC			VR	POTENTIOMETER	
1308, 1309, 1312,	50WV	0.01 μ F	1501, 1502	SR-19R	470 Ω B
1314~1316					
CERAMIC TC			C	CAPACITOR	
1303	500WV	5PF UJ		CERAMIC DISC	
1304	500WV	10PF UJ	1504	50WV	0.001 μ F
1301	500WV	20PF UJ	1507,	50WV	0.01 μ F
1305	500WV	82PF NPO		MYLAR	
CERAMIC FEED THRU			1509	50WV	0.01 μ F
1317	ECK-L1H102PE	1000PF			
VC VARIABLE CAPACITOR			ELECTROLYTIC		
1301	C521		1506	16WV	10 μ F
TC TRIMMER CAPACITOR			1503	16WV	100 μ F
1301	MC10P×2		1508	16WV	220 μ F
1302	KC-30P		1505	16WV	470 μ F
L INDUCTOR			1501, 1502	25WV	2200 μ F
1301	# 221025A				
1302	EL0610-680K	68 μ H			
1303	EL0610-251K	250 μ H			
REG UNIT			KEYING UNIT		
PB PRINTED CIRCUIT BOARD			PB	PRINTED CIRCUIT BOARD	
1469 (A~Z)	REG CIRCUIT BOARD		1568 (A~Z)		
Q TRANSISTOR			IC & TRANSISTOR		
1502, 1505	2SC372Y		1601	IC	TP4011AN
1503	2SC735Y		1602	Tr	2SC372Y
1501, 1504	2SD313D(2SD235O, Y)				
D DIODE			R RESISTOR		
1501	Si Bridge	M4B-5	1601, 1603	$\frac{1}{4}$ W	1K Ω
1505	Zener	WZ-061	1602	$\frac{1}{4}$ W	47K Ω
1502		WZ-090			
1503		WZ-110			
1504	Thyristor	CW-01B			
R RESISTOR			C CAPACITOR		
CARBON FILM			1601	16WV	10 μ F
1509	$\frac{1}{4}$ W	220 Ω			
1511	$\frac{1}{4}$ W	270 Ω			
1501	$\frac{1}{4}$ W	330 Ω			
1512	$\frac{1}{4}$ W	470 Ω			
1505	$\frac{1}{4}$ W	560 Ω			
1502	$\frac{1}{4}$ W	680 Ω			
1503	$\frac{1}{4}$ W	820 Ω			
1508	$\frac{1}{4}$ W	1K Ω			
1504	$\frac{1}{4}$ W	2.7K Ω			
1510	$\frac{1}{4}$ W	2.2K Ω			
1506	$\frac{1}{4}$ W	3.3K Ω			
WIRE WOUND					
1507	1 W	0.4 Ω			

